

FAST RECOVERY DIODES
Hockey Puk Version
Features

- High power FAST recovery diode series
- 1.0 to 1.5 μs recovery time
- High voltage ratings up to 1600V
- High current capability
- Optimized turn on and turn off characteristics
- Low forward recovery
- Fast and soft reverse recovery
- Press-puk encapsulation
- Case style conform to JEDEC DO-200AA
- Maximum junction temperature 125°C

Typical Applications

- Snubber diode for GTO
- High voltage free-wheeling diode
- Fast recovery rectifier applications

430A



case style DO-200AA

Major Ratings and Characteristics

Parameters	SD403C..C	Units	
$I_{F(AV)}$	430	A	
@ T_{hs}	55	°C	
$I_{F(RMS)}$	675	A	
@ T_{hs}	25	°C	
I_{FSM}	@ 50Hz	6180	A
	@ 60Hz	6470	A
I^2t	@ 50Hz	191	KA ² s
	@ 60Hz	175	KA ² s
V_{RRM} range	400 to 1600	V	
t_{rr} range	1.0 to 1.5	μs	
@ T_J	25	°C	
T_J	- 40 to 125	°C	

SD403C..C Series

ELECTRICAL SPECIFICATIONS

Voltage Ratings

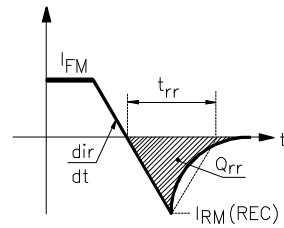
Type number	Voltage Code	V_{RRM} max. repetitive peak and off-state voltage V	V_{RSM} , maximum non-repetitive peak voltage V	I_{RRM} max. $T_J = 125^\circ\text{C}$ mA
SD403C..S10C	04	400	500	35
	08	800	900	
	10	1000	1100	
SD403C..S15C	12	1200	1300	
	14	1400	1500	
	16	1600	1700	

Forward Conduction

Parameter	SD403C..C	Units	Conditions
$I_{F(AV)}$ Max. average forward current @ Heatsink temperature	430(210)	A	180° conduction, half sine wave.
	55(75)	$^\circ\text{C}$	Double side (single side) cooled
$I_{F(RMS)}$ Max. RMS current	675	A	@ 25°C heatsink temperature double side cooled
I_{FSM} Max. peak, one-cycle non-repetitive forward current	6180	A	t = 10ms No voltage reappplied
	6470		t = 8.3ms reappplied
	5200		t = 10ms 100% V_{RRM} reappplied
	5445		t = 8.3ms reappplied
I^2t Maximum I^2t for fusing	191	KA^2s	t = 10ms No voltage reappplied
	175		t = 8.3ms reappplied
	135		t = 10ms 100% V_{RRM} reappplied
	123		t = 8.3ms reappplied
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing	1910	KA^2/s	t = 0.1 to 10ms, no voltage reappplied
$V_{F(TO)1}$ Low level of threshold voltage	1.00	V	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$, $T_J = T_J \text{ max.}$
$V_{F(TO)2}$ High level of threshold voltage	1.20		$(I > \pi \times I_{F(AV)})$, $T_J = T_J \text{ max.}$
r_{f1} Low level of forward slope resistance	0.56	$\text{m}\Omega$	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$, $T_J = T_J \text{ max.}$
r_{f2} High level of forward slope resistance	0.70		$(I > \pi \times I_{F(AV)})$, $T_J = T_J \text{ max.}$
V_{FM} Max. forward voltage	1.83	V	$I_{pk} = 1350\text{A}$, $T_J = 25^\circ\text{C}$, $t_p = 10\text{ms}$ sinusoidal wave

Recovery Characteristics

Code	$T_J = 25^\circ\text{C}$ typical t_{rr} @ 25% I_{RRM} (μs)	Test conditions			Max. values @ $T_J = 125^\circ\text{C}$		
		I_{pk} Square Pulse (A)	di/dt (A/ μs)	V_r (V)	t_{rr} @ 25% I_{RRM} (μs)	Q_{rr} (μC)	I_{rr} (A)
S10	1.0	750	25	-30	2.4	52	33
S15	1.5				2.9	90	44



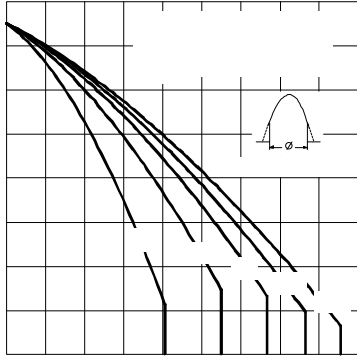


Fig. 3 - Current Ratings Characteristics

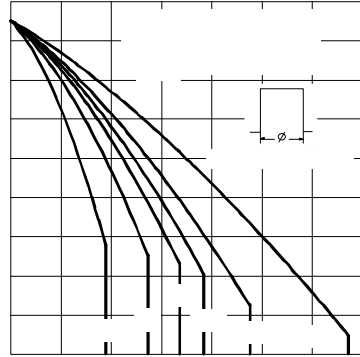


Fig. 4 - Current Ratings Characteristics

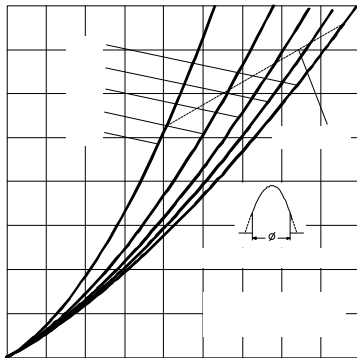


Fig. 5 - Forward Power Loss Characteristics

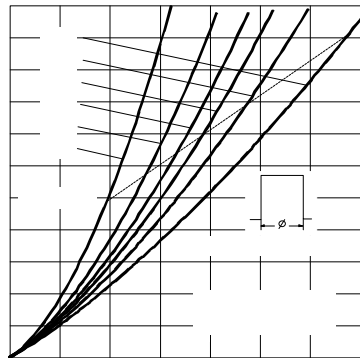


Fig. 6 - Forward Power Loss Characteristics

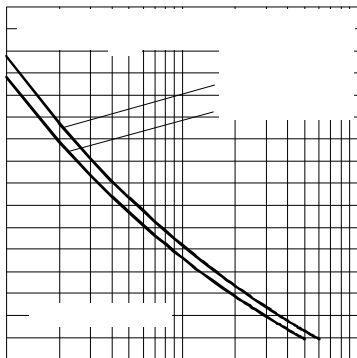


Fig. 7 - Maximum Non-repetitive Surge Current
Single and Double Side Cooled

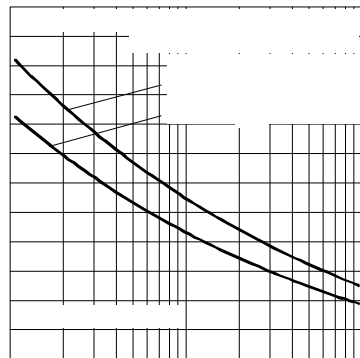


Fig. 8 - Maximum Non-repetitive Surge Current
Single and Double Side Cooled

SD403C..C Series

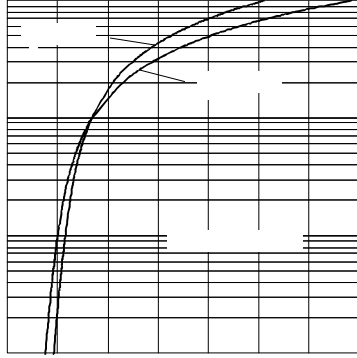


Fig. 9 - Forward Voltage Drop Characteristics

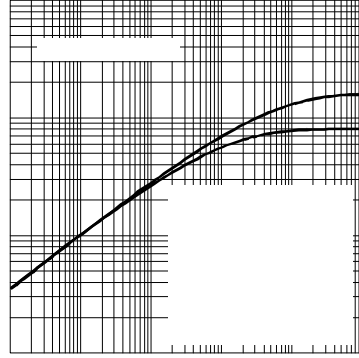


Fig. 10 - Thermal Impedance Z_{thJ-hs} Characteristic

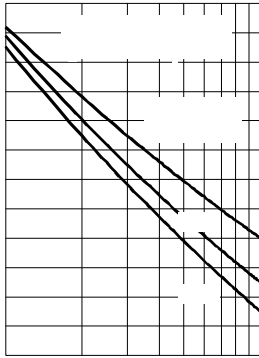


Fig. 11 - Recovery Time Characteristics

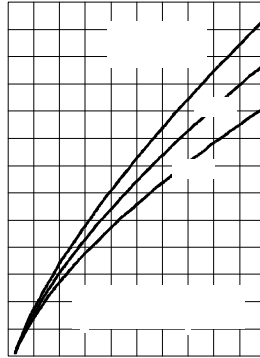


Fig. 12 - Recovery Charge Characteristics

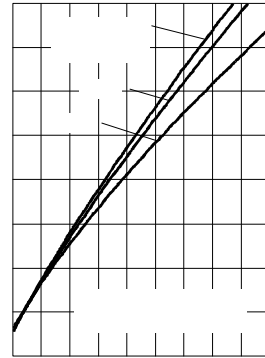


Fig. 13 - Recovery Current Characteristics

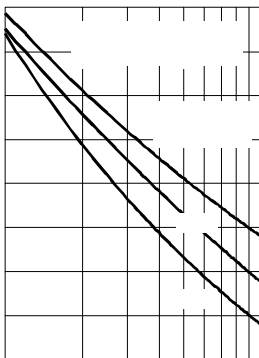


Fig. 14 - Recovery Time Characteristics

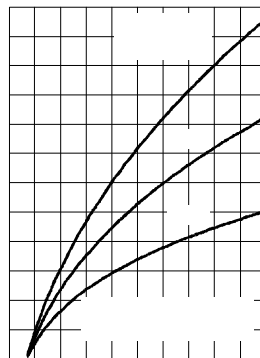


Fig. 15 - Recovery Charge Characteristics

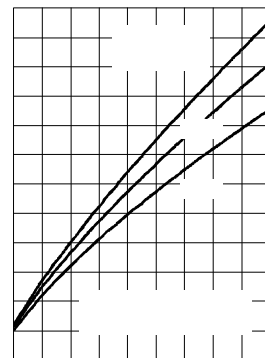


Fig. 16 - Recovery Current Characteristics

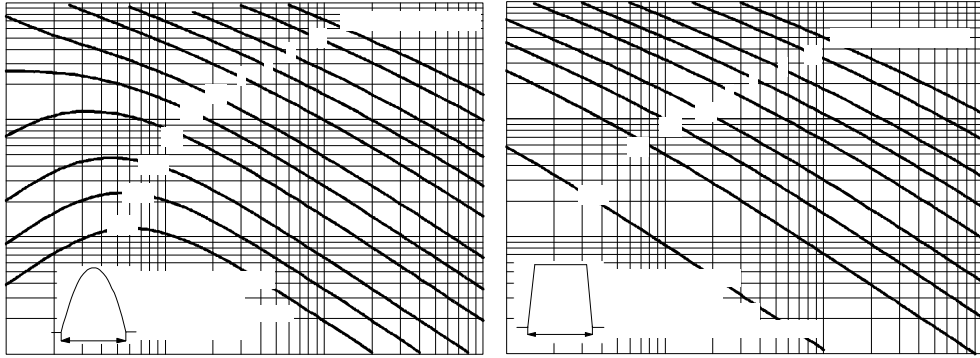


Fig. 17 - Maximum Total Energy Loss Per Pulse Characteristics

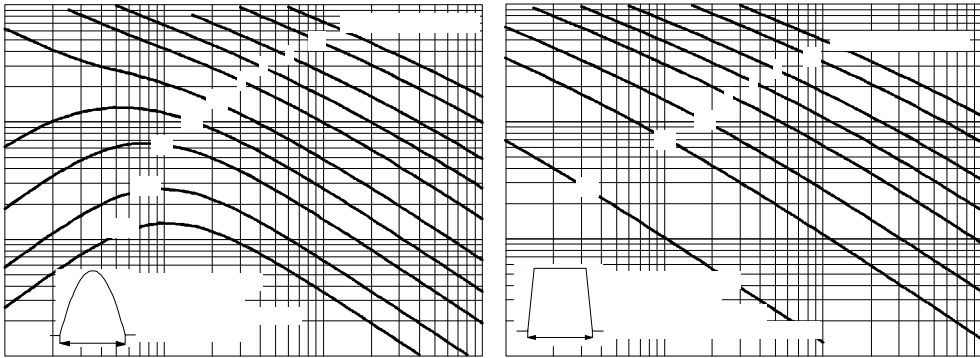


Fig. 18 - Maximum Total Energy Loss Per Pulse Characteristics

Thermal and Mechanical Specifications

Parameter	SD403C..C	Units	Conditions
T_J Max. operating temperature range	-40 to 125	°C	
T_{stg} Max. storage temperature range	-40 to 150		
R_{thJ-hs} Max. thermal resistance, junction to heatsink	0.16	K/W	DC operation single side cooled
	0.08		DC operation double side cooled
F Mounting force, $\pm 10\%$	4900 (500)	N (Kg)	
wt Approximate weight	70	g	
Case style	DO-200AA		See Outline Table

 ΔR_{thJ-hs} Conduction

(The following table shows the increment of thermal resistance R_{thJ-hs} when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction		Rectangular conduction		Units	Conditions
	Single Side	Double Side	Single Side	Double Side		
180°	0.010	0.011	0.008	0.008	K/W	$T_J = T_J \text{ max.}$
120°	0.012	0.013	0.013	0.013		
90°	0.016	0.016	0.018	0.018		
60°	0.024	0.024	0.025	0.025		
30°	0.042	0.042	0.042	0.042		

Ordering Information Table

Device Code	
SD 40 3 C 16 S15 C	
1	- Diode
2	- Essential part number
3	- 3 = Fast recovery
4	- C = Ceramic Puk
5	- Voltage code: Code x 100 = V_{RRM} (see Voltage Ratings table)
6	- t_{rr} code (see Recovery Characteristics table)
7	- C = Puk Case DO-200AA

SD403C..C Series

Outline Table

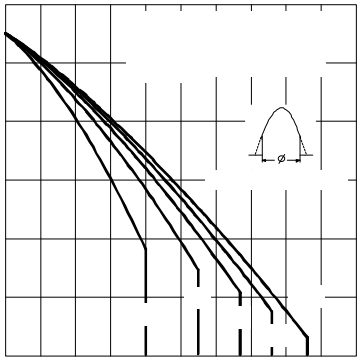
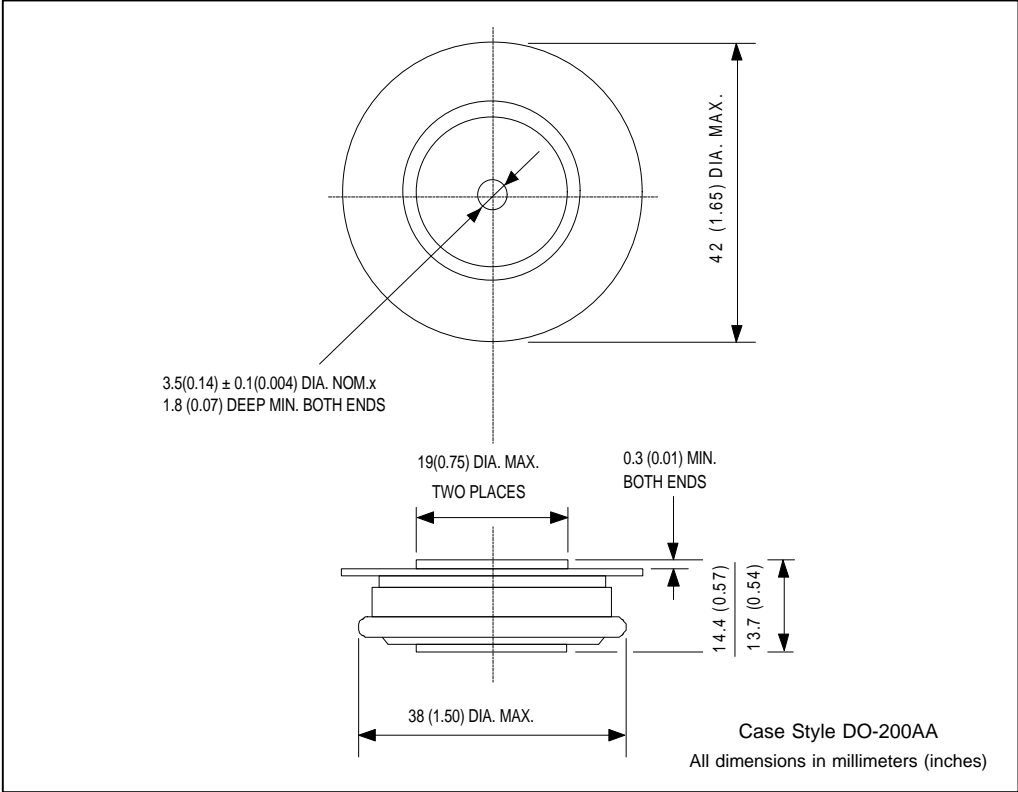


Fig. 1 - Current Ratings Characteristics

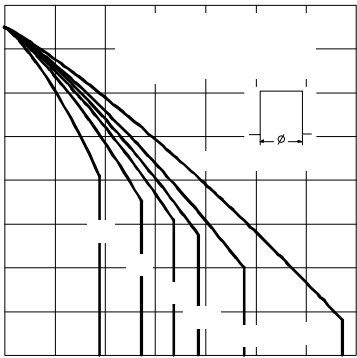


Fig. 2 - Current Ratings Characteristics